

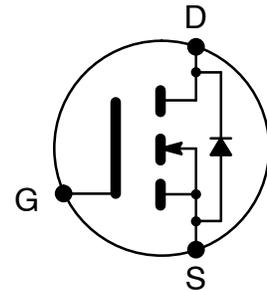


ELECTRONICS, INC.
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NTE2967 MOSFET N-Channel, Enhancement Mode High Speed Switch TO3P Type Package

Applications:

- Motor Control
- Lamp Control
- Solenoid Control
- DC-DC Converter



Absolute Maximum Ratings: ($T_C = +25^\circ\text{C}$ unless otherwise specified)

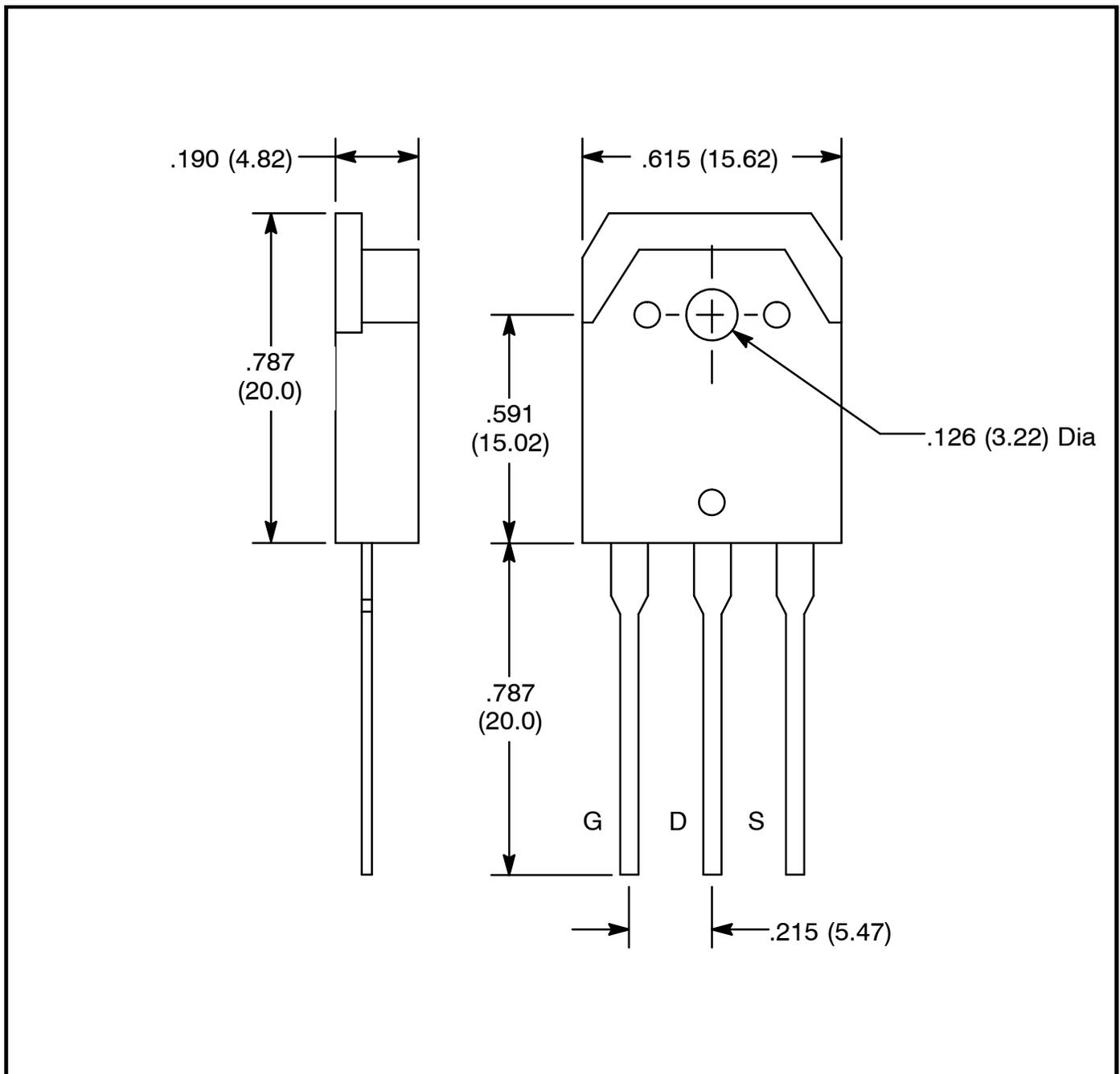
Drain-Source Voltage ($V_{GS} = 0\text{V}$), V_{DSS}	100V
Gate-Source Voltage ($V_{DS} = 0\text{V}$), V_{GS}	$\pm 20\text{V}$
Drain Current, I_D	
Continuous	70A
Pulsed	280A
Avalanche Drain Current (Pulsed, $L = 100^\circ\text{H}$), I_{DA}	70A
Source Current, I_S	
Continuous	70A
Pulsed	280A
Maximum Power Dissipation, P_D	150W
Channel Temperature Range, T_{ch}	-55° to $+150^\circ\text{C}$
Storage Temperature Range, T_{stg}	-55° to $+150^\circ\text{C}$
Thermal Resistance, Channel-to-Case, $R_{th(ch-c)}$	0.83°C/W

Electrical Characteristics: ($T_{ch} = +25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{DS} = 0\text{V}$, $I_D = 1\text{mA}$	100	-	-	V
Gate-Source Leakage	I_{GSS}	$V_{GS} = \pm 20\text{V}$, $V_{DS} = 0\text{V}$	-	-	± 0.1	$^\circ\text{A}$
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 100\text{V}$, $V_{GS} = 0$	-	-	0.1	mA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = 10\text{V}$, $I_D = 1\text{mA}$	2.0	3.0	4.0	V
Static Drain-Source ON Resistance	$R_{DS(on)}$	$V_{GS} = 10\text{V}$, $I_D = 35\text{A}$	-	14	20	$\text{m}\Omega$
Drain-Source On-State Voltage	$V_{DS(on)}$	$V_{GS} = 10\text{V}$, $I_D = 35\text{A}$	-	0.49	0.70	V
Forward Transfer Admittance	$ y_{fs} $	$V_{GS} = 10\text{V}$, $I_D = 35\text{A}$	-	53	-	S

Electrical Characteristics (Cont'd): ($T_{ch} = +25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Input Capacitance	C_{iss}	$V_{GS} = 0\text{V}, V_{DS} = 10\text{V}, f = 1\text{MHz}$	-	6540	-	pF
Output Capacitance	C_{oss}		-	1150	-	pF
Reverse Transfer Capacitance	C_{rss}		-	500	-	pF
Turn-On Delay Time	$t_{d(on)}$	$V_{DD} = 50\text{V}, I_D = 35\text{A}, V_{GS} = 10\text{V}, R_{GEN} = R_{GS} = 50\pm$	-	95	-	ns
Rise Time	t_r		-	175	-	ns
Turn-Off Delay Time	$t_{d(off)}$		-	330	-	ns
Fall Time	t_f		-	190	-	ns
Diode Forward Voltage	V_{SD}	$I_S = 35\text{A}, V_{GS} = 0\text{V}$	-	1.0	1.5	V
Reverse Recovery Time	t_{rr}	$I_S = 70\text{A}, dI_F/dt = 100\text{A}/^{\circ}\text{s}$	-	120	-	ns



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